

SU120-25



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Overview

In today's challenging Industrial environment, there is a need that SSDs must posses high endurance and reliability for heavy loading and write-intensive Embedded, IPC, HealthCare and networking systems. Apacer SU120-25 SATA SSD is engineered to meet the demanding need by adopting Apacer proprietary SLC lite technology. It utilizes the infrastructure of MLC flash to simulate the performance and durability of SLC flash. This exclusive design strikes a cost-performance balance between MLC and SLC flash types, making SU120-25 an ideal alternative solution for mission-critical Embedded and Industrial applications.



Feature

- SLC lite Technology
- Wide Temperature support
- Built-in S.M.A.R.T. Functions
- Intelligent Power Failure Recovery
- DEVSLP Support (Optional)
- 7mm Housing

Apacer

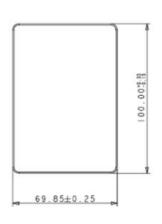
Specifications

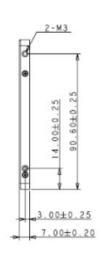
Interface SATA 3.0 (6Gb/s) Connector (7+15) pin male Form Factor 2.5 NAND Flash Type MLC Capacity 16GB~128GB External DRAM No Sustained Read Performance (MB/sec) Up to 430 Sustained Write Performance (MB/sec) Up to 190 ECC Engine Built-in 72-bit per 1K bytes BCH ECC IOPs (4K Random Write) 22K Standard Operating Temperature (*C) Thermal sensor No Shock Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Non-operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) MTBF (hours) >1,000,000	Model	SU120-25
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External DRAM Sustained Read Performance (MB/sec) Sustained Write Performance (MB/sec) ECC Engine Built-in 72-bit per 1K bytes BCH ECC IOPs (4K Random Write) 22K Standard Operating Temperature (°C) Extended Operating Temperature (°C) -40 ~ + 85 Storage Temperature (°C) Thermal sensor No Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Vibration Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) 100 x 69.8 x 7 (mm)	NAND Flash Type	MLC
Sustained Read Performance (MB/sec) Sustained Write Performance (MB/sec) ECC Engine Built-in 72-bit per 1K bytes BCH ECC IOPs (4K Random Write) 22K Standard Operating Temperature (°C) Extended Operating Temperature (°C) -40 ~ + 85 Storage Temperature (°C) Thermal sensor No Operation: 50G, 11ms Non-operation: 150G, 0.5ms Vibration Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H)	Capacity	16GB~128GB
Sustained Write Performance (MB/sec) ECC Engine Built-in 72-bit per 1K bytes BCH ECC 1OPs (4K Random Write) 22K Standard Operating Temperature (°C) Extended Operating Temperature (°C) -40 ~ + 85 Storage Temperature (°C) Thermal sensor No Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Vibration Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) 100 x 69.8 x 7 (mm)	External DRAM	No
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Standard Operating Temperature (°C) Extended Operating Temperature (°C) -40 ~ + 85 Storage Temperature (°C) Thermal sensor No Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Vibration Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) 100 x 69.8 x 7 (mm)	ECC Engine	Built-in 72-bit per 1K bytes BCH ECC
Extended Operating Temperature (°C) -40 ~ + 85 Storage Temperature (°C) -40 ~ + 85 Thermal sensor No Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) 100 x 69.8 x 7 (mm)	IOPs (4K Random Write)	22K
Storage Temperature (°C) -40 ~ + 85 Thermal sensor No Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) 100 x 69.8 x 7 (mm)	Standard Operating Temperature (°C)	0~+70
Thermal sensor Shock Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) 100 x 69.8 x 7 (mm)	Extended Operating Temperature (°C)	-40 ~ + 85
Shock Operation: 50G, 11ms Non-operation: 1500G, 0.5ms Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 15 G, 10 ~ 2000 Hz/sine Operating Voltage 5.0 V ± 5% Power Consumption Active mode: 320 mA & Idle mode: 75 mA Dimension (L x W x H) 100 x 69.8 x 7 (mm)	Storage Temperature (°C)	-40 ~ + 85
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Dimension (L x W x H) 100 x 69.8 x 7 (mm)	Operating Voltage	5.0 V ± 5%
	Power Consumption	Active mode: 320 mA & Idle mode: 75 mA
MTBF (hours) >1,000,000	Dimension (L x W x H)	100 x 69.8 x 7 (mm)
	MTBF (hours)	>1,000,000

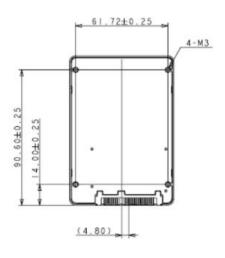
Apacer

Mechanical Specification











Unit: mm

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